

**TC74HC151AP, TC74HC151AF, TC74HC151AFN****8 - CHANNEL MULTIPLEXER**

The TC74HC151A is a high speed CMOS 8 - CHANNEL MULTIPLEXER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

One of eight date input signals (D0 - D7) is selected by decoding of the three - bit address input (A, B, C). The selected data appears on two outputs : non - inverting (Y) and inverting (W).

The strobe input provides two output conditions ; a low level on the strobe input transfers the selected data to the outputs. A high level on the strobe input sets the Y output low and the W output high without regard to the data or select input conditions.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

**FEATURES :**

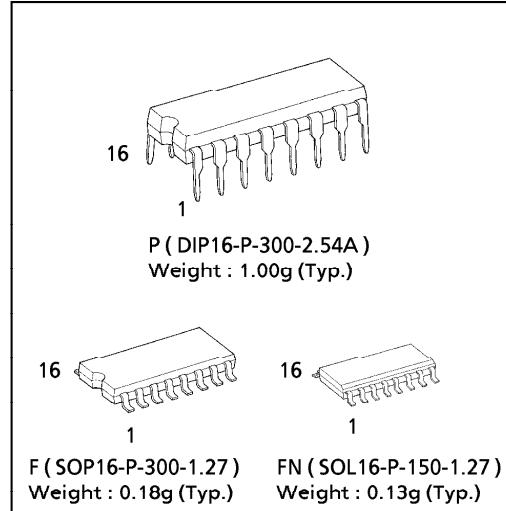
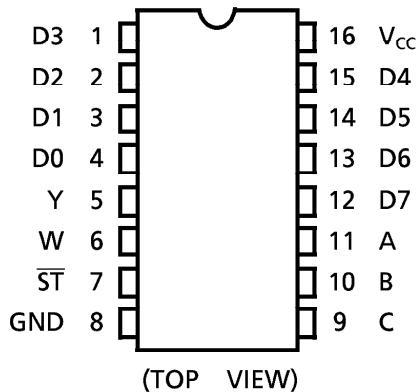
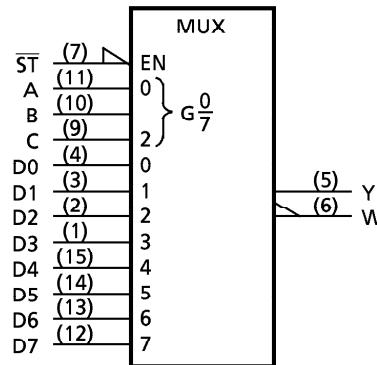
- High Speed..... $t_{pd} = 15\text{ns}(\text{typ.})$  at  $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$  at  $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Output Drive Capability.....10 LSTTL Loads
- Symmetrical Output Impedance..... $|I_{OH}| = |I_{OL}| = 4\text{mA}(\text{Min.})$
- Balanced Propagation Delays..... $t_{pLH} = t_{pHL}$
- Wide Operating Voltage Range..... $V_{CC}$  (opr.) = 2V ~ 6V
- Pin and Function Compatible with 74LS151

**TRUTH TABLE**

INPUTS			OUTPUTS		
SELECT			STROBE	Y	W
C	B	A	$\bar{ST}$		
X	X	X	H	L	H
L	L	L	L	D0	$\bar{D}0$
L	L	H	L	D1	$\bar{D}1$
L	H	L	L	D2	$\bar{D}2$
L	H	H	L	D3	$\bar{D}3$
H	L	L	L	D4	$\bar{D}4$
H	L	H	L	D5	$\bar{D}5$
H	H	L	L	D6	$\bar{D}6$
H	H	H	L	D7	$\bar{D}7$

X : Don't Care

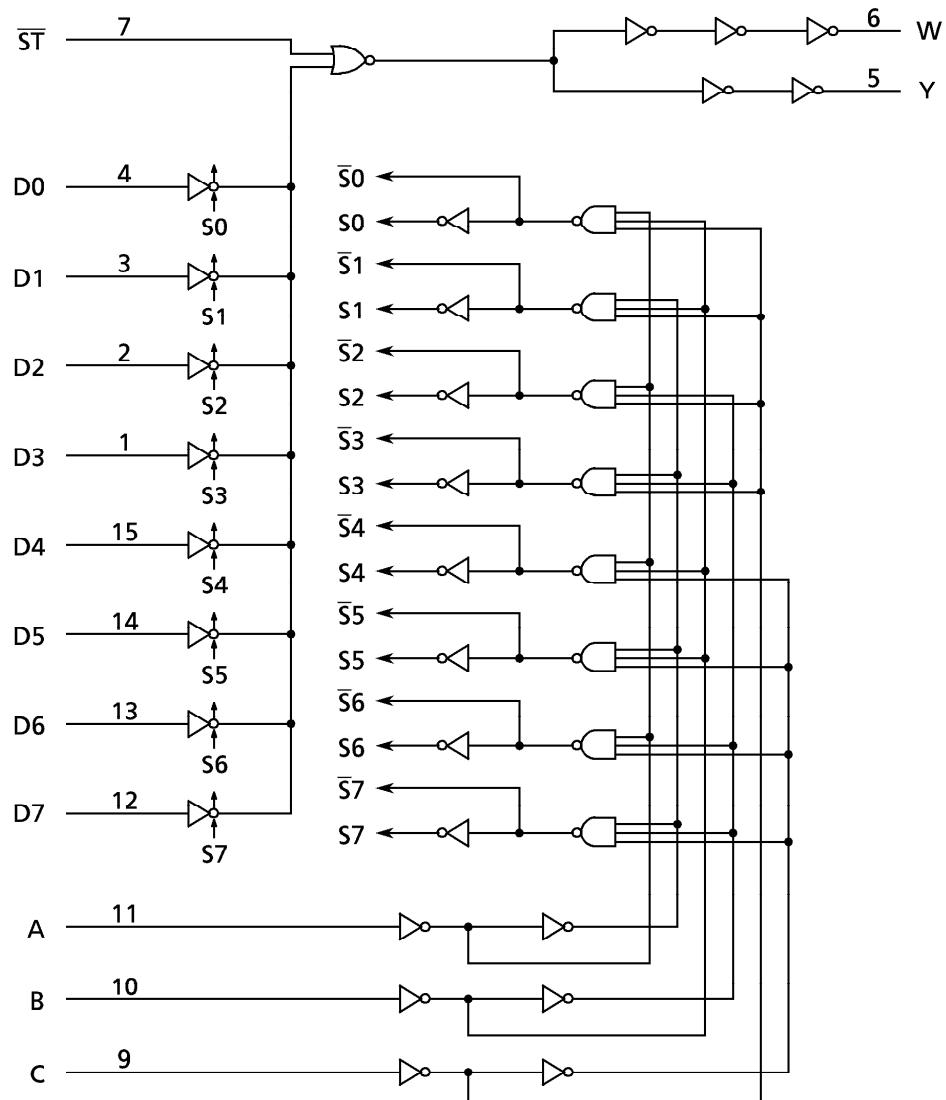
(Note) The JEDEC SOP (FN) is not available in Japan.

**PIN ASSIGNMENT****IEC LOGIC SYMBOL**

961001EBA2

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## SYSTEM DIAGRAM



961001EBA2'

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## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC} + 0.5$	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 20$	mA
DC Output Current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}$ / Ground Current	$I_{CC}$	$\pm 50$	mA
Power Dissipation	$P_D$	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	$T_{stg}$	-65~150	°C

\*500mW in the range of  $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$ . From  $T_a = 65^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  shall be applied until 300mW.

## RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2~6	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$t_r, t_f$	0~ 1000 ( $V_{CC} = 2.0\text{V}$ ) 0~ 500 ( $V_{CC} = 4.5\text{V}$ ) 0~ 400 ( $V_{CC} = 6.0\text{V}$ )	ns

## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	$V_{IH}$		2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	— — —	V
Low - Level Input Voltage	$V_{IL}$		2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — —	0.50 1.35 1.80	V
High - Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -20\mu\text{A}$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	— — —	1.9 4.4 5.9	V
			$I_{OH} = -4\text{ mA}$ $I_{OH} = -5.2\text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	— —	4.13 5.63	
Low - Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 20\mu\text{A}$	2.0 4.5 6.0	0.0 0.0 0.0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	V
			$I_{OL} = 4\text{ mA}$ $I_{OL} = 5.2\text{ mA}$	4.5 6.0	0.17 0.18	0.26 0.26	— —	0.33 0.33	
Input Leakage Current	$I_{IN}$	$V_{IN} = V_{CC}$ or GND	6.0	—	—	$\pm 0.1$	—	$\pm 1.0$	$\mu\text{A}$
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	6.0	—	—	4.0	—	40.0	

AC ELECTRICAL CHARACTERISTICS ( $C_L = 15\text{pF}$ ,  $V_{CC} = 5\text{V}$ ,  $T_a = 25^\circ\text{C}$ , Input  $t_r = t_f = 6\text{ns}$ )

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	$t_{TLH}$ $t_{THL}$		—	4	8	ns
Propagation Delay Time (D-Y)	$t_{pLH}$ $t_{pHL}$		—	15	24	
Propagation Delay Time (D-W)	$t_{pLH}$ $t_{pHL}$		—	15	24	
Propagation Delay Time ( $\bar{S}\bar{T}$ -Y)	$t_{pLH}$ $t_{pHL}$		—	10	17	
Propagation Delay Time ( $\bar{S}\bar{T}$ -W)	$t_{pLH}$ $t_{pHL}$		—	10	17	
Propagation Delay Time (A, B, C-Y)	$t_{pLH}$ $t_{pHL}$		—	19	31	
Propagation Delay Time (A, B, C-W)	$t_{pLH}$ $t_{pHL}$		—	19	31	

AC ELECTRICAL CHARACTERISTICS ( $C_L = 50\text{pF}$ , Input  $t_r = t_f = 6\text{ns}$ )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	$t_{TLH}$		2.0	—	30	75	—	95	ns
	$t_{THL}$		4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation Delay Time (D-Y)	$t_{pLH}$		2.0	—	65	140	—	175	
	$t_{pHL}$		4.5	—	18	28	—	35	
			6.0	—	15	24	—	30	
Propagation Delay Time (D-W)	$t_{pLH}$		2.0	—	65	140	—	175	
	$t_{pHL}$		4.5	—	18	28	—	35	
			6.0	—	15	24	—	30	
Propagation Delay Time ( $\bar{S}\bar{T}$ -Y)	$t_{pLH}$		2.0	—	36	100	—	125	
	$t_{pHL}$		4.5	—	12	20	—	25	
			6.0	—	10	17	—	21	
Propagation Delay Time ( $\bar{S}\bar{T}$ -W)	$t_{pLH}$		2.0	—	36	100	—	125	
	$t_{pHL}$		4.5	—	12	20	—	25	
			6.0	—	10	17	—	21	
Propagation Delay Time (A, B, C-Y)	$t_{pLH}$		2.0	—	80	180	—	225	
	$t_{pHL}$		4.5	—	23	36	—	45	
			6.0	—	19	31	—	38	
Propagation Delay Time (A, B, C-W)	$t_{pLH}$		2.0	—	80	180	—	225	
	$t_{pHL}$		4.5	—	23	36	—	45	
			6.0	—	19	31	—	38	
Input Capacitance	$C_{IN}$			—	5	10	—	10	pF
Power Dissipation Capacitance	$C_{PD}$ (1)			—	69	—	—	—	

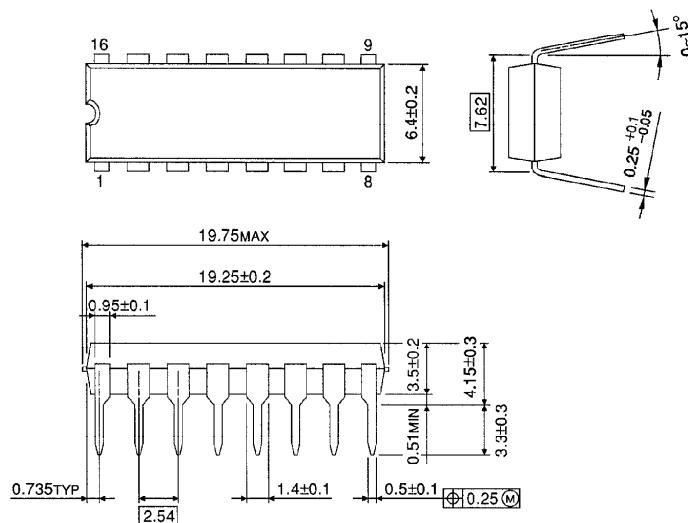
Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A )

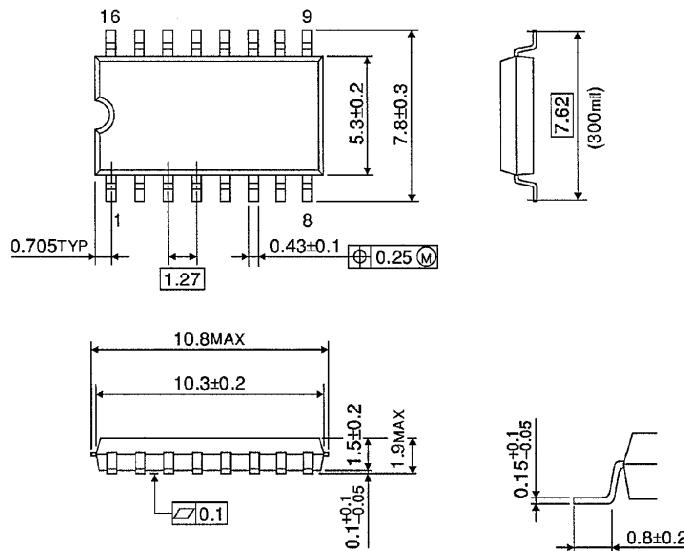
Unit in mm



Weight : 1.00g (Typ.)

## SOP 16PIN ( 200mil BODY ) OUTLINE DRAWING ( SOP16-P-300-1.27 )

Unit in mm

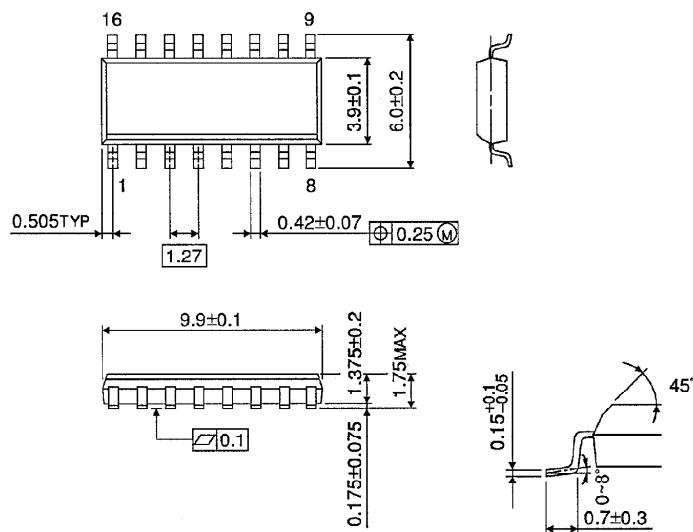


Weight : 0.18g (Typ.)

## SOP 16PIN ( 150mil BODY ) OUTLINE DRAWING ( SOL14-P-150 -1.27)

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)